

Reg. No:

--	--	--	--	--	--	--	--	--	--

SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGY:: PUTTUR
(AUTONOMOUS)

B.Tech I Year II Semester Supplementary Examinations July-2021

SEMICONDUCTOR PHYSICS

(Common to ECE, CSE & CSIT)

Time: 3 hours

Max. Marks: 60

PART-A

(Answer all the Questions 5 x 2 = 10 Marks)

- | | | |
|---|---|----|
| 1 | a Formulate Fermi-Dirac distribution function. | 2M |
| | b Define Hall effect. | 2M |
| | c Illustrate the direct band gap of semiconductors. | 2M |
| | d List the characteristics of laser. | 2M |
| | e Write various structures of carbon nano tubes. | 2M |

PART-B

(Answer all Five Units 5 x 10 = 50 Marks)

UNIT-I

- | | | |
|---|---|----|
| 2 | a Differentiate direct and indirect band gap of semiconductors. | 5M |
| | b Explain the Fermi-Dirac distribution function. | 5M |

OR

- | | | |
|---|--|----|
| 3 | a What are Brillouin zones? List the corresponding values for a wave vector of first and second Brillouin zones. | 5M |
| | b Write the brief note on effective mass of an electron. | 5M |

UNIT-II

- | | | |
|---|--|----|
| 4 | a What is intrinsic semiconductor? Derive the expression for intrinsic charge carrier concentration. | 5M |
| | b Discuss the effect of temperature on Fermi level of an extrinsic semiconductor. | 5M |

OR

- | | | |
|---|---|----|
| 5 | a Derive the Einstein's relation in semiconductor. | 5M |
| | b Distinguish between ohmic contact and Schottky barriers in junction diodes. | 5M |

UNIT-III

- | | | |
|---|--|----|
| 6 | a Elaborate radiative and non-radiative mechanisms in semiconductors. | 5M |
| | b Describe the charge carrier separation mechanism in photo detectors. | 5M |

OR

- | | | |
|---|---|----|
| 7 | a Outline the principle and characteristics of Avalanche diode. | 5M |
| | b Discuss the structure and working mechanism of Avalanche diode. | 5M |

UNIT-IV

- | | | |
|---|---|----|
| 8 | a Develop the relation between various Einstein's coefficients of absorption and emission of radiation. | 6M |
| | b Explain the different pumping mechanisms in laser. | 4M |

OR

- | | | |
|---|--|----|
| 9 | a What is numerical aperture of an optical fiber and derive the expression for it. | 5M |
| | b Differentiate step index and graded index fibers. | 5M |

UNIT-V

- | | | |
|----|---|----|
| 10 | a What are nanomaterials? Write the classification of nanomaterials. | 5M |
| | b Explain why surface area to volume ratio is very large for nanomaterials. | 5M |

OR

- | | | |
|----|--|----|
| 11 | a What are carbon nanotubes? Mention its structure. | 5M |
| | b What is Graphene? Write a brief note on its properties | 5M |

END